SCIENTIFIC REPORTS

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Publisher Correction: Observation of photobleaching in Ge-deficient $\text{Ge}_{16.8}\text{Se}_{83.2}$ chalcogenide thin film with prolonged irradiation

Sen Zhang^{1,2}, Yimin Chen^{1,2,3}, Rongping Wang^{1,2,4}, Xiang Shen^{1,2} & Shixun Dai^{1,2}

Correction to: *Scientific Reports* <https://doi.org/10.1038/s41598-017-14796-w>, published online 03 November 2017

The original HTML version of this Article contained a typographical error in the publication date '03 November 2017' which was incorrectly given as '06 November 2017'. This has now been corrected in the HTML version of the Article.

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¹Laboratory of Infrared Materials and Devices, Ningbo University, Ningbo, Zhejiang, 315211, China. ²Key Laboratory of Photoelectric Detection Materials and Devices of Zhejiang Province, Ningbo, 315211, China. ³University of Chinese Academy of Sciences, Beijing, 100049, China. ⁴Laser Physics Centre, The Australian National University, Acton, Canberra, ACT, 2605, Australia. Correspondence and requests for materials should be addressed to R.W. (email: wangrongping@nbu.edu.cn) or X.S. (email: shenxiang@nbu.edu.cn)